|  |   | - AK   | _                   |
|--|---|--|---------------------|
|  | Application No.   | Applicant(s)   |                     |
|  | 09/998,787  | BAO ET AL.   |                     |
| Notice of Allowability   | Examiner  | Art Unit   |                     |
|  | Pamela E Perkins  | 2822   |                     |
| The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313 | (OR REMAINS) CLOSED in this ap<br>or other appropriate communication<br>IGHTS. This application is subject to | plication. If not included<br>n will be mailed in due course |                     |
| 1. This communication is responsive to the filing of the amend   | dment on 16 December 2003.  |  |                     |
| 2. The allowed claim(s) is/are <u>1-29</u> .   |   |  |                     |
| 3. The drawings filed on 31 October 2001 are accepted by the   |   |  |                     |
| <ul> <li>4. ☐ Acknowledgment is made of a claim for foreign priority un</li> <li>a) ☐ All b) ☐ Some* c) ☐ None of the:</li> </ul>  | nder 35 U.S.C. § 119(a)-(d) or (f).   |  |                     |
| <ol> <li>Certified copies of the priority documents have</li> </ol>  | been received.  |  |                     |
| <ol><li>Certified copies of the priority documents have</li></ol>  | been received in Application No   | ·  |                     |
| <ol><li>Copies of the certified copies of the priority do</li></ol>  | cuments have been received in this  | national stage application fro                               | m the               |
| International Bureau (PCT Rule 17.2(a)).   |   |  |                     |
| * Certified copies not received:   |   |  |                     |
| <ol> <li>Acknowledgment is made of a claim for domestic priority un<br/>reference was included in the first sentence of the specifica</li> </ol>   | nder 35 U.S.C. § 119(e) (to a provis<br>ation or in an Application Data Sheel                                 | ional application) since a spe<br>i. 37 CFR 1.78.            | cific               |
| (a) The translation of the foreign language provisional a  | • •   |  |                     |
| 6. Acknowledgment is made of a claim for domestic priority ur in the first sentence of the specification or in an Application  |   | nce a specific reference was                                 | included            |
| Applicant has THREE MONTHS FROM THE "MAILING DATE" of below. Failure to timely comply will result in ABANDONMENT of  | this communication to file a reply contribution that the communication. THIS THREE-MO                         | omplying with the requiremen<br>NTH PERIOD IS NOT EXTEN      | its noted<br>NDABLE |
| 7. A SUBSTITUTE OATH OR DECLARATION must be subminiformal PATENT APPLICATION (PTO-152) which give  | itted. Note the attached EXAMINER es reason(s) why the oath or declara  | 'S AMENDMENT or NOTICE ation is deficient.                   | OF                  |
| <ul> <li>8.  CORRECTED DRAWINGS (as "replacement sheets") mus</li> <li>(a) including changes required by the Notice of Draftspers</li> <li>1) hereto or 2) to Paper No</li> <li>(b) including changes required by the proposed drawing or</li> </ul>   | on's Patent Drawing Review ( PTO-   | -948) attached<br>een approved by the Examine                | ar.                 |
| (c) ☐ including changes required by the attached Examiner's  | <del></del>   |  |                     |
| Identifying indicia such as the application number (see 37 CFR 1. each sheet. Replacement sheet(s) should be labeled as such in the  | .84(c)) should be written on the drawin   | ngs in the front (not the back) o                            |                     |
| 9. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT FOR T   | sit of BIOLOGICAL MATERIAL I<br>HE DEPOSIT OF BIOLOGICAL MA   | nust be submitted. Note the                                  | 9                   |
| Attachment(s)  |   |  |                     |
| 1☐ Notice of References Cited (PTO-892)  | 5⊡ Notice of Informal Pa  | atent Application (PTO-152)                                  |                     |
| <ul> <li>2 Notice of Draftperson's Patent Drawing Review (PTO-948)</li> <li>3 Information Disclosure Statements (PTO-1449 or PTO/SB/08 Paper No.</li> </ul>  |   | PTO-413), Paper No   |                     |
|  | ), 7 Examiner's Amendm  | ent/Comment  |                     |
| 4 Examiner's Comment Regarding Requirement for Deposit of Biological Material  | 8⊠ Examiner's Statemer  | nt of Reasons for Allowance                                  |                     |
|  |   | Lher Jac   |                     |
|  |   | Michael Trinh 1/9/04<br>imary Examiner                       |                     |
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## **DETAILED ACTION**

This office action is in response to the filing of the amendment on 16 December 2003. Claims 1-29 are pending.

## Allowable Subject Matter

Claims 1-29 are allowed.

## Reasons for Allowance

The following is an examiner's statement of reasons for allowance: prior art does not anticipate, teach, or suggest a method of copper metallization in the fabrication of an integrated circuit device where an opening is formed in a dielectric layer; forming a copper layer in the opening; coating an oxide layer on the dielectric layer, copper layer and on the walls of a deposition chamber; heating the structure in the deposition chamber and depositing a capping layer over the oxide layer.

For example, Ngo et al. (6,472,755) disclose a method of copper metallization in the fabrication of an integrated circuit device where an opening is formed in a dielectric layer overlying a substrate; forming a copper layer within the opening; coating the copper layer with an oxide layer and depositing a silicon nitride or silicon carbide capping layer on the oxide layer. Ngo et al. further disclose heating the substrate in a deposition chamber using a NH<sub>3</sub> plasma. Ngo et al. also disclose forming the copper layer using a physical vapor deposition (PVD) process, a chemical vapor deposition (CVD) process, electroplating or electroless plating. However, Ngo et al. do not

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disclose, anticipate, teach, or suggest coating an oxide layer on the dielectric layer, copper layer and on the walls of a deposition chamber; heating the structure in the deposition chamber and depositing a capping layer over the oxide layer.

Givens et al. (6,080,655) disclose a method of copper metallization where an opening is formed in a dielectric layer overlying a substrate; forming a copper layer within and over the opening; using a CMP process to polish back the copper layer to only within the opening and then depositing a capping layer on the copper layer. Given et al. further disclose forming the copper layer using a PVD process, a CVD process, electroplating or electroless plating. Givens et al. also disclose the substrate having semiconductor structures such as gate electrodes, source and drain regions, lower level metallization and the opening connecting the a semiconductor structure. However, Givens et al. do not disclose, anticipate, teach or suggest coating an oxide layer on the dielectric layer, copper layer and on the walls of a deposition chamber; heating the structure in the deposition chamber and depositing a capping layer over the oxide layer.

The prior art made of record in this action does not anticipate, teach, or suggest a method of copper metallization in the fabrication of an integrated circuit device where an opening is formed in a dielectric layer; forming a copper layer in the opening; coating an oxide layer on the dielectric layer, copper layer and on the walls of a deposition chamber; heating the structure in the deposition chamber and depositing a capping layer over the oxide layer.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably Application/Control Number: 09/998,787

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accompany the issue fee. Such submissions should be clearly labeled "Comments on

Statement of Reasons for Allowance."

Conclusion

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Pamela E Perkins whose telephone number is (703)

605-4299. The examiner can normally be reached on Monday thru Friday, 9:00am to

5:30pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Amir Zarabian can be reached on (703) 308-4905. The fax phone number

for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is (703) 308-

0956.

Michael Trinh

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**Primary Examiner** 

PEP